MOSFETs Silicon P-Channel MOS (U-MOSⅥ)

SSM3J140TU

1. Applications

- Power Management Switches

2. Features

(1) AEC-Q101 qualified

(2) 1.5-V gate drive voltage.

(3) Low drain-source on-resistance

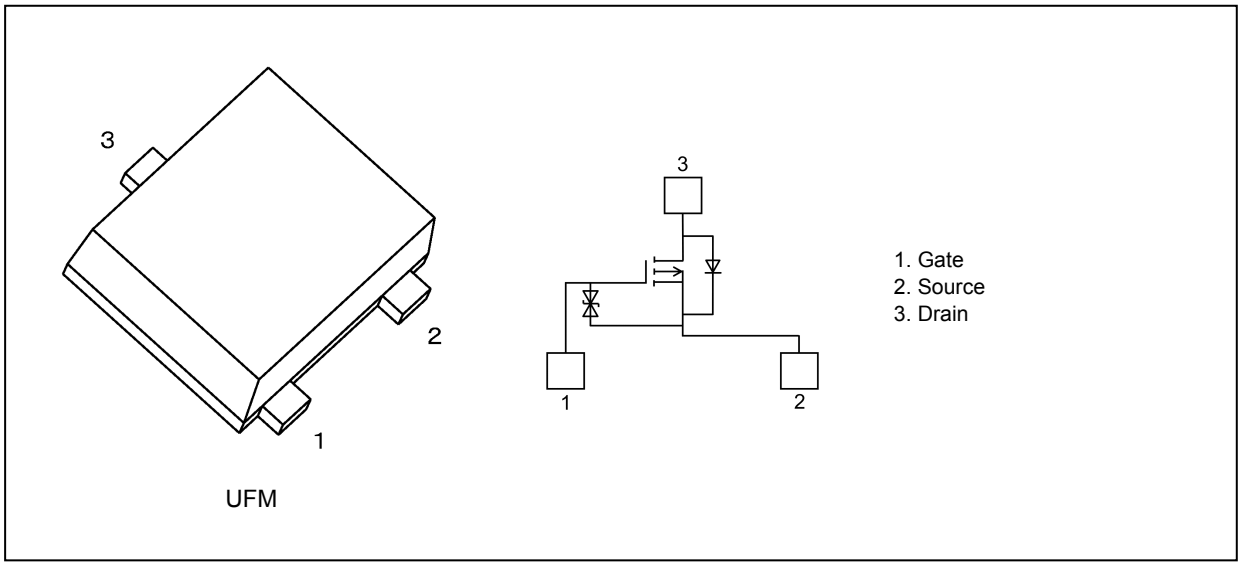
$R_{DS(ON)}$ = 63.2 mΩ (max) (@V_{GS} = -1.5 V)

$R_{DS(ON)}$ = 41.1 mΩ (max) (@V_{GS} = -1.8 V)

$R_{DS(ON)}$ = 31.0 mΩ (max) (@V_{GS} = -2.5 V)

$R_{DS(ON)}$ = 25.8 mΩ (max) (@V_{GS} = -4.5 V)

3. Packaging and Pin Configuration



Start of commercial production

2017-10

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4. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	-20	V
Gate-source voltage			V_{GSS}	-8/+6	
Drain current (DC)		(Note 1)	I_D	-4.4	A
Drain current (pulsed)		(Note 1), (Note 2)	I_{DP}	-8.8	
Power dissipation		(Note 3)	P_D	500	mW
Power dissipation	(t < 1 s)	(Note 3)	P_D	1000	mW
Channel temperature			T_{ch}	150	°C
Storage temperature			T_{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Pulse width (PW) ≤ 10 ms, duty ≤ 1 %

Note 3: Device mounted on an FR4 board.(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm^2)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, $R_{th(ch-a)}$, and the drain power dissipation, P_D, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

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5. Electrical Characteristics

5.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	V_{GS} = -8/+6 V, V_{DS} = 0 V	—	—	±1	μA
Drain cut-off current		I_{DSS}	V_{DS} = -20 V, V_{GS} = 0 V	—	—	-1	
Drain-source breakdown voltage		$V_{(BR)DSS}$	I_D = -1 mA, V_{GS} = 0 V	-20	—	—	V
Drain-source breakdown voltage	(Note 1)	$V_{(BR)DSX}$	I_D = -1 mA, V_{GS} = 5 V	-15	—	—	
Gate threshold voltage	(Note 2)	V_{th}	V_{DS} = -3 V, I_D = -1 mA	-0.3	—	-1.0	
Drain-source on-resistance	(Note 3)	$R_{DS(ON)}$	I_D = -4.0 A, V_{GS} = -4.5 V	—	20.9	25.8	mΩ
			I_D = -4.0 A, V_{GS} = -2.5 V	—	24.2	31.0	
			I_D = -2.5 A, V_{GS} = -1.8 V	—	28.8	41.1	
			I_D = -1.5 A, V_{GS} = -1.5 V	—	32.4	63.2	
Forward transfer admittance	(Note 3)	$\|Y_{fs}\|$	V_{DS} = -3 V, I_D = -2.0 A	8.8	17.5	—	S

Note 1: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (-1 mA for this device). Then, for normal switching operation, $V_{GS(ON)}$ must be higher than V_{th}, and $V_{GS(OFF)}$ must be lower than V_{th}. This relationship can be expressed as: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$.
Take this into consideration when using the device.

Note 3: Pulse measurement.

5.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz	—	1800	—	pF
Reverse transfer capacitance	C_{rss}		—	190	—	
Output capacitance	C_{oss}		—	205	—	
Switching time (turn-on time)	t_{on}	V_{DD} = -10 V, I_D = -1.5 A V_{GS} = 0 to -2.5 V, R_{GS} = 4.7 Ω Duty ≤ 1 %, Input: t_r, t_f < 5 ns Common source	—	25	—	ns
Switching time (turn-off time)	t_{off}		—	133	—	

5.3. Switching Time Test Circuit

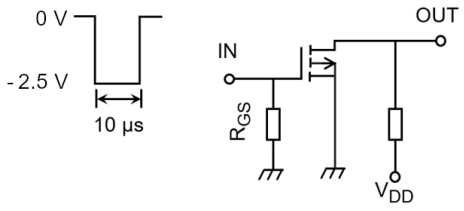


Fig. 5.3.1 Test Circuit of Switching Time

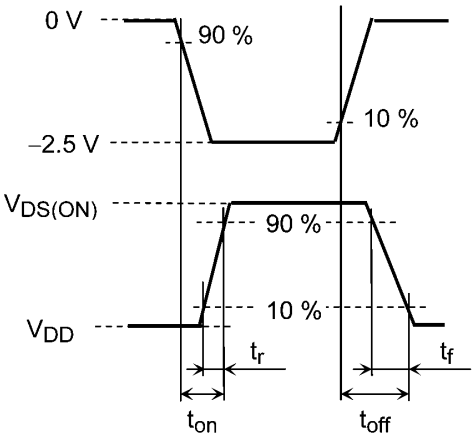


Fig. 5.3.2 Input Waveform/Output Waveform

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5.4. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	V_{DD} = -10 V, V_{GS} = -4.5 V, I_D = -4.4 A	—	24.8	—	nC
Gate-source charge 1	Q_{gs1}		—	1.0	—	
Gate-drain charge	Q_{gd}		—	6.8	—	

5.5. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	V_{DSF}	I_D = 4.4 A, V_{GS} = 0 V	—	0.83	1.2	V

Note 1: Pulse measurement.

6. Marking

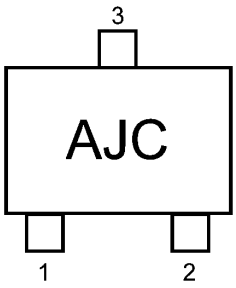


Fig. 6.1 Marking

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7. Characteristics Curves (Note)

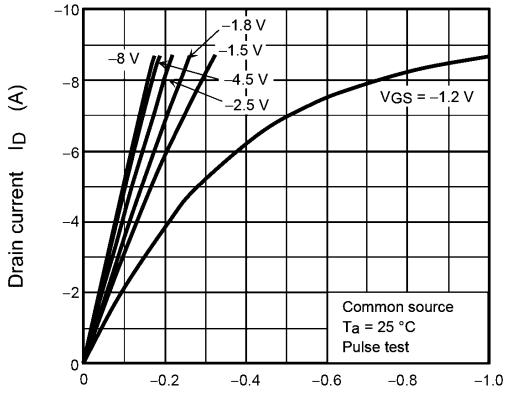


Fig. 7.1 I_D - V_{DS}

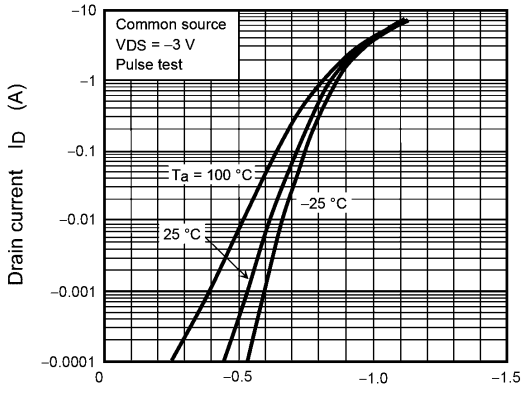


Fig. 7.2 I_D - V_{GS}

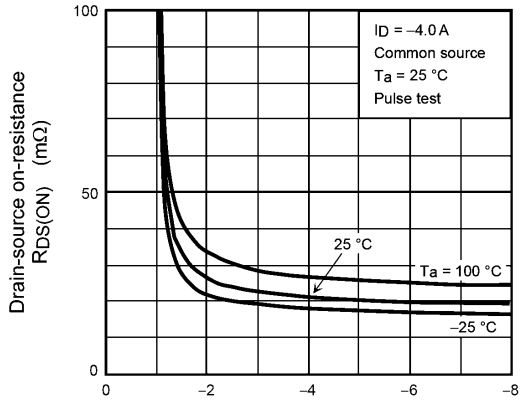


Fig. 7.3 $R_{DS(ON)}$ - V_{GS}

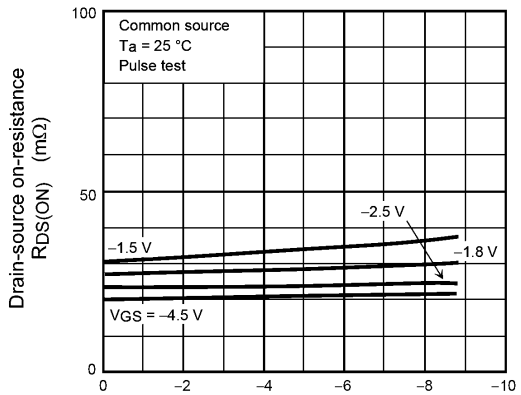


Fig. 7.4 $R_{DS(ON)}$ - I_D

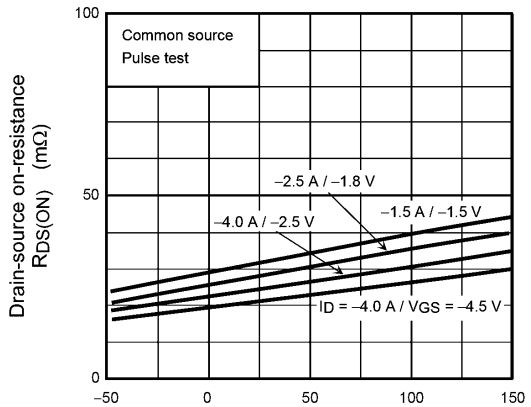


Fig. 7.5 $R_{DS(ON)}$ - T_a

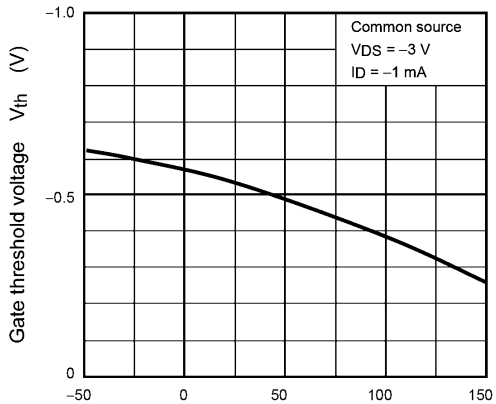


Fig. 7.6 V_{th} - T_a

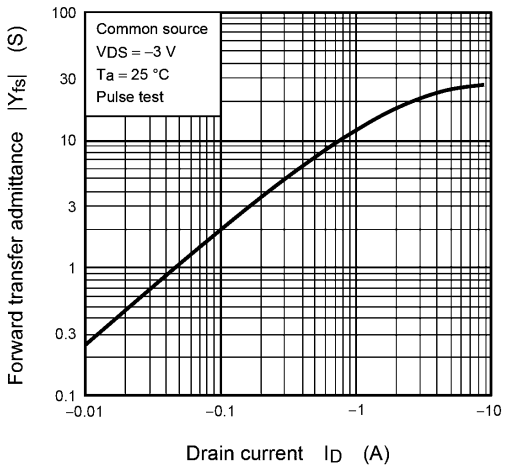


Fig. 7.7 $|Y_{fs}|$ - I_D

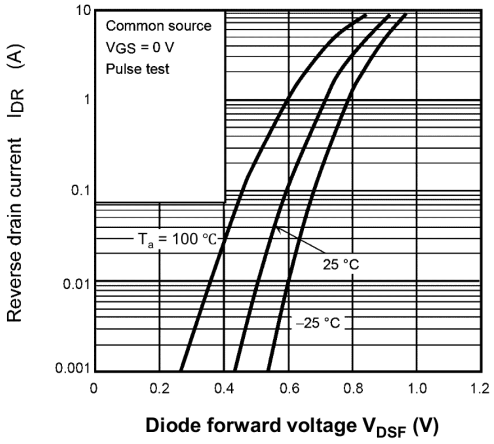


Fig. 7.8 I_{DR} - V_{DSF}

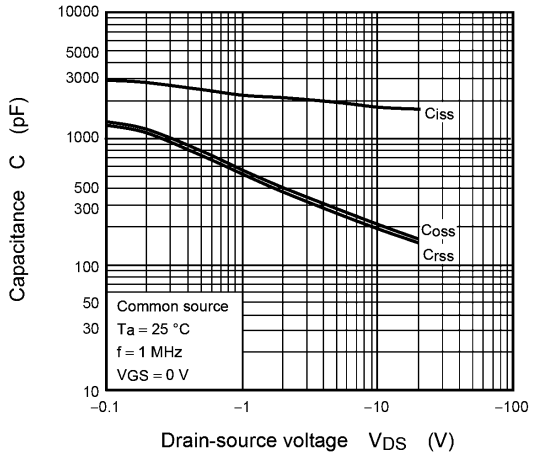


Fig. 7.9 C - V_{DS}

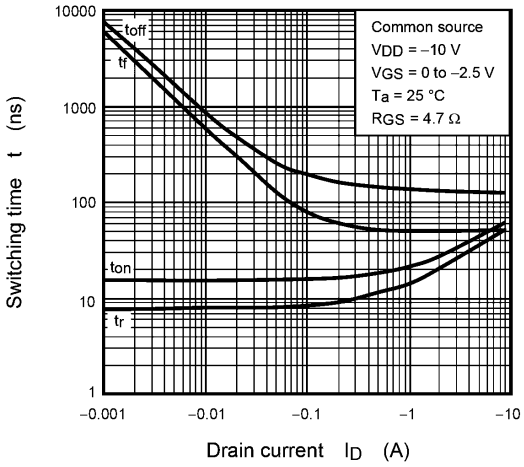


Fig. 7.10 t - I_D

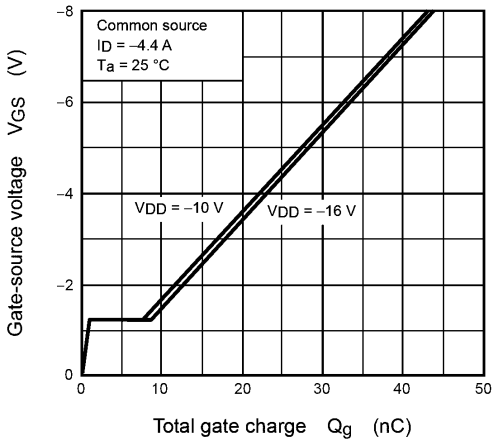


Fig. 7.11 Dynamic Input Characteristics

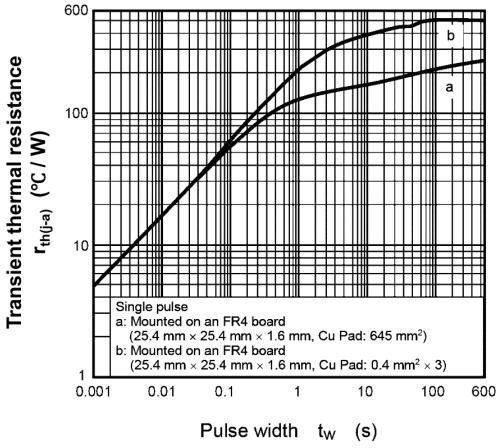


Fig. 7.12 $r_{th(j-a)}$ - t_w

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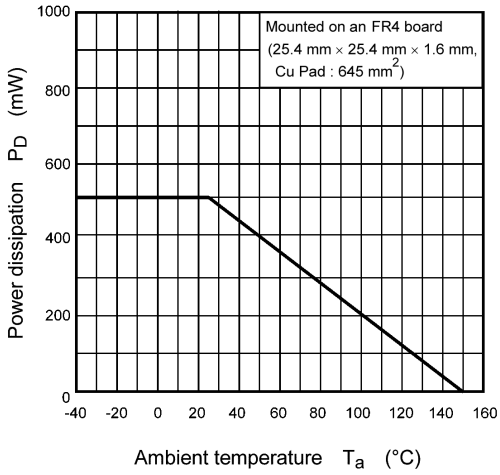


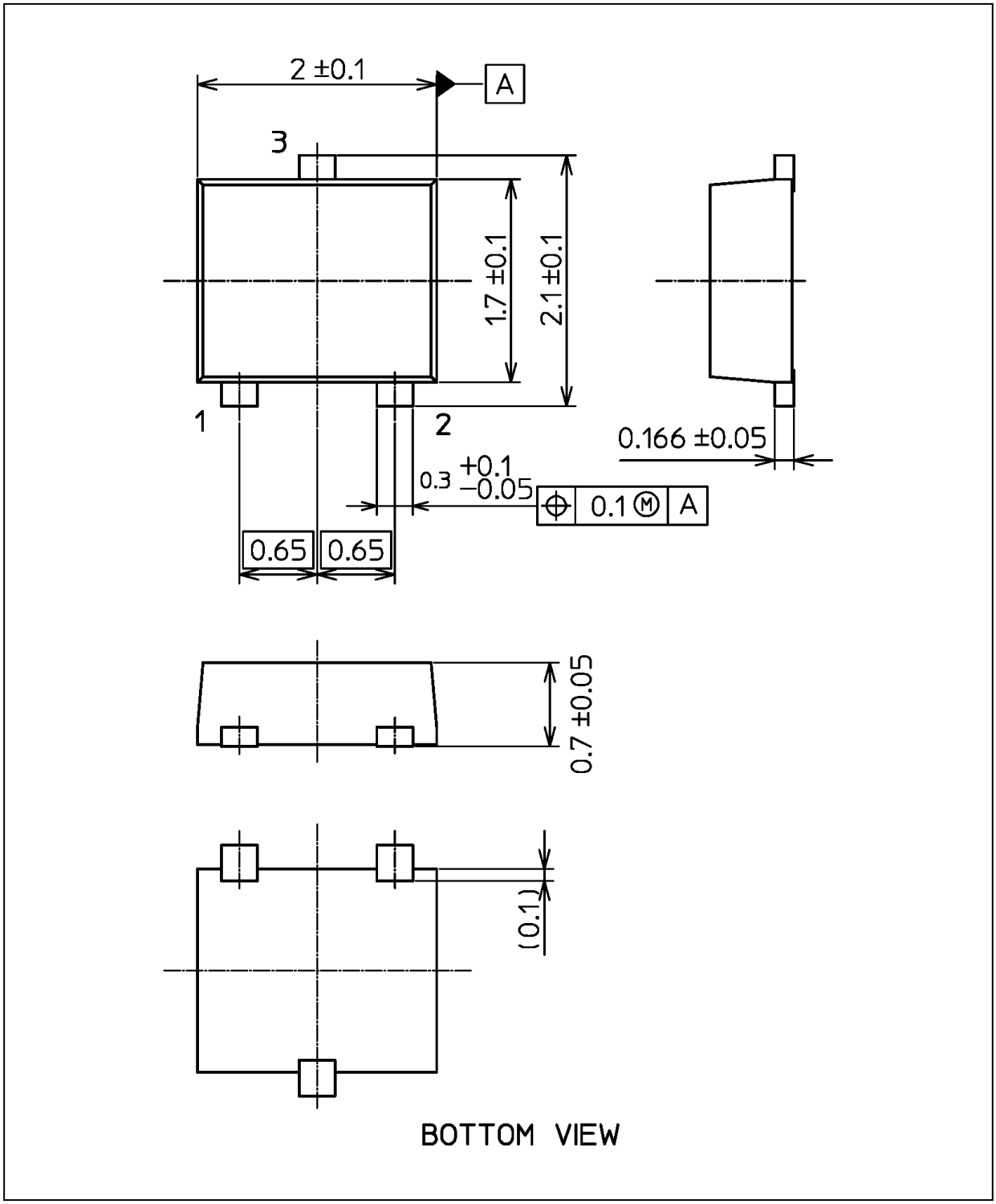
Fig. 7.13 P_D - T_a

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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Package Dimensions

Unit: mm



Weight: 6.6 mg (typ.)

Package Name(s)
Nickname: UFM

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